NSN 5961-00-431-6830

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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.350 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-emitter, base open and 1.0 collector to emitter saturation voltage

Current Rating Per Characteristic:

30.00 amperes source cutoff current

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

20.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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